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Small Size, Low-Power, Unidirectional, CURRENT SHUNT MONITOR

 $\ddot{\bullet}$

Zerø**-Drift Series**

Check for Samples: [INA216](http://www.ti.com/product/ina216#samples)

- **² CHIP-SCALE PACKAGE**
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- **QUIESCENT CURRENT: 13**μ**A**
- **BUFFERED VOLTAGE OUTPUT: No Additional Op Amp Needed**

APPLICATIONS

- **NOTEBOOK COMPUTERS**
- **CELL PHONES**
- **TELECOM EQUIPMENT**
- **POWER MANAGEMENT**
- **BATTERY CHARGERS**

¹FEATURES DESCRIPTION

The INA216 is a high-side voltage output current shunt monitor that can sense drops across shunts at **COMMON-MODE RANGE: +1.8V to +5.5V**

common-mode voltages from +1.8V to +5.5V. Four

fixed gains are available: 25V/V, 50V/V, 100V/V, and fixed gains are available: 25V/V, 50V/V, 100V/V, and • **GAIN ERROR:** ±**0.2% MAX** 200V/V. The low offset of the Zerø-Drift architecture enables current sensing with maximum drops across **CHOICE OF GAINS:**

- **INA216A1: 25V/V** The shunt as low as 10mV full-scale, or with wide

- **INA216A1: 25V/V** the shunt as low as 10mV full-scale, or with wide dynamic ranges of over 1000:1.

– **INA216A2: 50V/V** These devices operate from ^a single +1.8V to +5.5V power supply, drawing a maximum of 25µA of supply – **INA216A4: 200V/V** current. The INA216 series are specified over the temperature range of –40°C to +125°C, and offered in a chip-scale package.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE INFORMATION(1)

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device [product](http://focus.ti.com/docs/prod/folders/print/ina216.html) folder at [www.ti.com.](http://www.ti.com)

ABSOLUTE MAXIMUM RATINGS(1)

Over operating free-air temperature range, unless otherwise noted.

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

 V_{1N+} and V_{1N-} are the voltages at the IN+ and IN– pins, respectively.

(3) Input voltage at any pin may exceed the voltage shown if the current at that pin is limited to 5mA.

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THERMAL INFORMATION

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, [SPRA953](http://www.ti.com/lit/pdf/spra953).

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PIN CONFIGURATIONS

(1) No internal connection.

- (2) Bump side down. Drawing not to scale.
- (3) Power supply is derived from shunt (minimum common-mode range = 1.8V)

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ELECTRICAL CHARACTERISTICS

Boldface limits apply over the specified temperature range, **T^A =** –**40**°**C to +125**°**C.** At T_A = +25°C and V_{CM} = V_{IN+} = 4.2V, unless otherwise noted.

(1) RTI: Referred-to-input.

(2) CMRR and PSRR are the same because V_{CM} is the supply voltage.
(3) See Typical Characteristics graph, *Output Swing to Rail* ([Figure](#page-6-0) 9).

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ELECTRICAL CHARACTERISTICS (continued)

Boldface limits apply over the specified temperature range, **T^A =** –**40**°**C to +125**°**C.**

At T_A = +25°C and V_{CM} = V_{IN+} = 4.2V, unless otherwise noted.

(4) RTI: Referred-to-input.

 $CMNR$ (W/V)

EXAS STRUMENTS

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TYPICAL CHARACTERISTICS

0.04

The INA216A1 is used for typical characteristic measurements at $T_A = +25^\circ C$, $V_S = +4.2V$, unless otherwise noted.

INPUT OFFSET VOLTAGE PRODUCTION DISTRIBUTION OFFSET VOLTAGE vs TEMPERATURE

COMMON-MODE REJECTION RATIO vs TEMPERATURE GAIN ERROR vs TEMPERATURE

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TYPICAL CHARACTERISTICS (continued)

The INA216A1 is used for typical characteristic measurements at $T_A = +25^\circ C$, $V_S = +4.2V$, unless otherwise noted.

OUTPUT VOLTAGE SWING vs OUTPUT CURRENT INPUT-REFERRED VOLTAGE NOISE vs FREQUENCY

STEP RESPONSE

EXAS STRUMENTS

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The INA216A1 is used for typical characteristic measurements at $T_A = +25^{\circ}C$, $V_S = +4.2V$, unless otherwise noted.

COMMON-MODE VOLTAGE TRANSIENT RESPONSE INVERTING DIFFERENTIAL INPUT OVERLOAD

Output Signal

Time $(100 \mu s/div)$

Noninverting Input Overload Signal

Noninverting Input Overload 50mV/div

Output 1V/div

APPLICATION INFORMATION

Basic Connections

[Figure](#page-8-0) 18 shows the basic connections of the INA216. The input pins, IN+ and IN–, should be connected as closely as possible to the shunt resistor to minimize any resistance in series with the shunt resistance.

resistor with additional trace resistance in series with and low-side current shunt monitor.
the shunt placed between where the current shunt low-side current shunt monitor. monitors the input pins. With the typically low shunt resistor values commonly used in these applications, **Selecting R_S** even small amounts of additional impedance in series The selection of the value of the shunt resistor (R_S) to with the shunt resistor can significantly affect the use with the INA216 is based on the specific with the shunt resistor can significantly affect the

Figure 20. Shunt Resistance Measurement Using a Kelvin Connection

Power Supply

The INA216 does not have a dedicated power-supply pin. Instead, an internal connection to the IN+ pin **Figure 18. Typical Application** serves as the power supply for this device. Because the INA216 is powered from the IN+ pin, the [Figure](#page-8-1) 19 illustrates the INA216 connected to a shunt common-mode input range is limited on the low end Figure 19 illustrates the INA216 connected to a shunt to 1.8V. Therefore, the INA216 cannot be used as a

differential voltage present at the INA216 input pins. The operating conditions and requirements of the application. The starting point for selecting the resistor is to first determine the desired full-scale output from the INA216. The INA216 is available in four gain options: 25, 50, 100, and 200. By dividing the desired full-scale output by each of the gain options, there are then four available differential input voltages that can achieve the desired full-scale output voltage, given that the appropriate gain device is used. With four values for the total voltage that is to be dropped across the shunt, the decision on how much of a drop is allowed in the application must be made. Most applications have a maximum drop allowed to ensure that the load receives the required **Figure 19. Shunt Resistance Measurement** voltage necessary to operate. Assuming that there **Including Trace Resistance, R_P** are now multiple shunt voltages that are acceptable (based on the design criteria), the choice of what
value shunt resistor to use can be made based on [Figure](#page-8-2) 20 shows a proper Kelvin, or four-wire,
connection of the shunt resistor to the INA216 input
pins. This connection helps ensure that the only
impedance between the current monitor input pins is
the shunt resistor.
t shunt voltage present at the current shunt monitor input, less error is introduced by the input offset voltage.

These comments have framed the decision on what **Calculating Total Error** the shunt resistor value should be, based on the
full-scale value; but many applications require
accurate measurements at levels as low as 10% of
the full-scale value. At this level, the input offset error, and nonlinearit

$$
Error_{\text{Os}} = \frac{V_{\text{os}}}{V_{\text{SENSE}}} \cdot 100 \tag{1}
$$

Ideally, the differential input voltage at 10% would be
increased to minimize the effects of the input offset
voltage; however, we are bound by the full-scale
value. The full-scale output voltage on the INA216 is
limited t monitor at the full-scale load current. For applications The typical error sources that have the largest impact where accuracy over a larger range is needed, a on the total error of the device are input offset lower gain option (and therefore, a larger differential voltage, common-mode voltage rejection, gain error, input voltage) is selected. For applications where a and nonlinearity error. input voltage) is selected. For applications where a

For example, consider a design that requires a crelatively constant throughout the linear input range of tull-
full-scale output voltage of 4V, a maximum load cthe device. While the gain error remains constant full-scale output voltage of 4V, a maximum load the device. While the gain error remains constant current of 10A, and a maximum voltage drop on the across the linear input range of the device, the error current of 10A, and a maximum voltage drop on the across the linear input range of the device, the error
common-mode line of 25mV. The 25mV maximum associated with the input offset voltage does not. As common-mode line of 25mV. The 25mV maximum voltage drop requirement and a 4V full-scale output the differential input voltage developed across a limits the gain option to the 200V/V device. A 100V/V shunt resistor at the input of the INA216 decreases, setting would require a maximum voltage drop of the inherent input offset voltage of the device
40mV with the other two lower gain versions creating becomes a larger percentage of the measured input 40mV with the other two lower gain versions creating becomes a larger percentage of the measured input larger voltage drops. Based on the gain of 200 on a signal, resulting in an increase in measurement error. larger voltage drops. Based on the gain of 200 on a signal, resulting in an increase in measurement error.
4V full-scale output, the maximum differential input This varying error is present among all current shunt 4V full-scale output, the maximum differential input This varying error is present among all current shunt voltage ratio to the voltage ratio to the voltage would be 20mV. The shunt resistor needed to monitors, given the input offset voltage ratio to the create a 20mV drop with a 10A load current is $2m\Omega$. voltage being sensed by the device. The low input

When choosing the proper shunt resistor, it is also
important to consider that at higher currents, the
voltage has on the total error term. power dissipation in the shunt resistor becomes greater. Therefore, it is important to evaluate the drift Two examples are provided that detail how different of the sense resistor as a result of power dissipation, operating conditions can affect the total error and choose an appropriate resistor based on its calculations. Typical and maximum calculations are power wattage rating. shown as well to provide the user more information

current shunt monitors specify a total error in the product data sheet. However, this total error term is accurate under only one particular set of operating

minimal voltage drop on the line that powers the load
is required, a higher gain option (and so, a smaller
differential input voltage) is selected.
results in a gain error that can be expected to be create a 20mV drop with a 10A load current is 2mΩ. voltage being sensed by the device. The low input
view offset voltages present in the INA216 devices,

> on how much error variance could be present from device to device.

Example 1

Conditions: INA216A3; $V_{CM} = V_s = 3.3V$; $V_{SENSE} = 20mV$

Table 1. Example 1

Example 2

Conditions: INA216A1; VCM = V^S = 5V; VSENSE = 160mV

Table 2. Example 2

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An ideal location where filtering is implemented is at
the inputs for a device. Placing an input filter in front
of the INA216, though, is not recommended but can
be implemented if it is determined to be necessary.
be imp This location is not recommended for filtering If filtering is required for the application and the gain because adding input filters induces an additional error introduced by the input filter resistors exceeds gain error to the device that can easily exceed the the available error budget for this circuit, a filter can device maximum gain error specification of 0.2%. In be implemented following the INA216. Placing a filter the INA216, the nominal current into the IN+ pin is in at the output of the current shunt monitor is not the range of 13μA while the bias current into the IN– typically the ideal location because the benefit of the pin is in the range of approximately 3μA. The current low impedance output of the amplifier is lost. flowing into the IN+ pin includes both the input bias Applications that require the low impedance output current as well as the quiescent current. Where the require an additional buffer amplifier that follows the issue of input filtering begins to become more of an post current shunt monitor filter. issue is that as the quiescent current of the INA216 also flows through the IN+ pin, when the output **Using the INA216 With Transients Above 5.5V** begins to drive current, this additional current also With a small amount of additional circuitry, INA216 flows through the IN+ pin, creating an even larger can be used in circuits subject to transients higher

with each input and a 0.1μ F capacitor across the as *Transzorbs*. Any other type of transient absorber input pins, as shown in Figure 21, introduces an all has an unacceptable time delay. To use these input pins, as shown in [Figure](#page-11-0) 21, introduces an las an unacceptable time delay. To use these inditional gain error into the system. For example, a protection devices, resistors are required in series consider an application using the INA216A3 with a with the INA216 inputs, as shown in [Figure](#page-11-1) 22. These full-scale output of 4V, assuming that the device is resistors serve as a working impedance for the zener.
That driving any output current. The shunt voltage it is desirable to keep these resistors as small as needed to create the 4V output with a gain of 100 is possible because of the error described in the *[Input](#page-11-2)* 40mV. With 10Ω filter resistors on each input, there is [Filtering](#page-11-2) section. These protection resistors are most a difference voltage created that subtracts from the often around 10Ω. Larger values can be used with a a difference voltage created that subtracts from the often around 10Ω. Larger values can be used with a 40mV full-scale differential current. The error can be express term and to the total gain error. Because this calculated using Equation 2.

 $Error_{\text{FUTER}} = \frac{(\vert_{\text{IN+}} - \vert_{\text{IN-}}) \cdot \text{R}_{\text{FUTER}}}{}$ + 100 V SHUNT

Figure 21. Input Filter

As mentioned previously, the current flowing into the IN+ pin increases once the output begins to drive current because of the quiescent current also flowing **Figure 22. Transient Protection Using Dual Zener** into the IN+ pin. The previous example resulted in an **Diodes** additional gain error of 0.3% as a result of the 10Ω filter resistors (assuming the output stage was not

Input Filtering driving any current). Connecting a 100kΩ load to the

error.
can be used in circuits subject to transients higher
Placing a typical common-mode filter of 10 Ω in series transient absorbers, which are sometimes referred to transient absorbers, which are sometimes referred to protection devices, resistors are required in series It is desirable to keep these resistors as small as circuit limits only short-term transients, many applications are satisfied with a 10Ω resistor along with conventional zener diodes of the lowest power (2) rating that can be found. This combination uses the least amount of board space. These diodes can be found in packages as small as SOT-523 or SOD-523. The use of these protection components may allow the INA216 to survive from being damaged in environments where large transients are common.

REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (June, 2010) to Revision B Page

EXAS **STRUMENTS**

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

PACKAGE OPTION ADDENDUM

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TEXAS

TAPE AND REEL INFORMATION

ISTRUMENTS

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

www.ti.com 9-Feb-2025

PACKAGE MATERIALS INFORMATION

PACKAGE OUTLINE

YFF0004 DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY

NOTES:

NanoFree Is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. NanoFree[™] package configuration.

EXAMPLE BOARD LAYOUT

YFF0004 DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY

NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).

EXAMPLE STENCIL DESIGN

YFF0004 DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

PACKAGE OUTLINE

RSW0010A UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package complies to JEDEC MO-288 variation UDEE, except minimum package height.

EXAMPLE BOARD LAYOUT

RSW0010A UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RSW0010A UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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